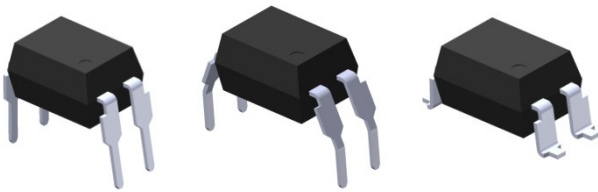
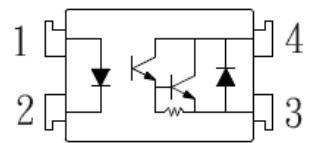


4 PIN DIP HIGH VOLTAGE PHOTODARLINGTON PHOTOCOUPLER EL852 Series



Schematic



Pin Configuration

1. Anode
2. Cathode
3. Emitter
4. Collector

Features:

- High collector- emitter voltage ($V_{CEO}=350V$)
- Current transfer ratio (CTR: 1000% min. at $I_F = 1mA$, $V_{CE} = 2V$)
- High isolation voltage between input and output ($V_{iso}=5000 V rms$)
- Creepage distance $>7.62 mm$
- Operating temperature up to $+110^{\circ}C$
- Compact small outline package
- Pb free and RoHS compliant.
- UL approved
- VDE approved
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved

Description

The EL852 series consists an infrared emitting diodes, optically coupled to a high voltage photo Darlington detector.

It is packaged in a 4-pin DIP package and available in wide-lead spacing and SMD option.

Applications

- Telephone set, telephone exchangers
- Sequence controllers
- System appliances, measuring instruments
- Signal transmission between circuits of different potentials and impedances

Absolute Maximum Ratings (Ta=25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I_F	60	mA
	Peak forward current (1us, pulse)	I_{FP}	1	A
	Reverse voltage	V_R	6	V
	Power dissipation No derating required up to Ta = 100°C	P_D	100	mW
Output	Power dissipation	P_C	300	mW
	Derating factor (above Ta = 80°C)		5.8	mW/°C
	Collector current	I_C	150	mA
	Collector-Emitter voltage	V_{CEO}	350	V
	Emitter-Collector voltage	V_{ECO}	0.1	V
Total power dissipation	P_{TOT}	200	mW	
Isolation voltage ^{*1}	V_{ISO}	5000	V rms	
Operating temperature	T_{OPR}	-55 ~ +110	°C	
Storage temperature	T_{STG}	-55 ~ +125	°C	
Soldering Temperature ^{*2}	T_{SOL}	260	°C	

Notes:

*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1 & 2 are shorted together, and pins 3 & 4 are shorted together.

*2 For 10 seconds

Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

Input

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Forward Voltage	V_F	-	1.2	1.4	V	$I_F = 10\text{mA}$
Reverse Current	I_R	-	-	10	μA	$V_R = 4\text{V}$
Input capacitance	C_{in}	-	30	250	pF	$V = 0, f = 1\text{kHz}$

Output

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Collector-Emitter dark current	I_{CEO}	-	-	200	nA	$V_{CE} = 200\text{V}, I_F = 0\text{mA}$
Collector-Emitter breakdown voltage	BV_{CEO}	350	-	-	V	$I_C = 0.1\text{mA}$
Emitter-Collector breakdown voltage	BV_{ECO}	0.1	-	-	V	$I_E = 0.1\text{mA}$

Transfer Characteristics

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Current Transfer ratio	CTR	1000	-	15000	%	$I_F = 1\text{mA}, V_{CE} = 2\text{V}$
Collector-Emitter saturation voltage	$V_{CE(sat)}$	-	-	1.2	V	$I_F = 20\text{mA}, I_C = 100\text{mA}$
Isolation resistance	R_{IO}	5×10^{10}	-	-	Ω	$V_{IO} = 500\text{Vdc}, 40\sim 60\% \text{ R.H.}$
Floating capacitance	C_{IO}	-	0.6	1.0	pF	$V_{IO} = 0, f = 1\text{MHz}$
Cut-off frequency	f_c	-	7	-	kHz	$V_{CE} = 2\text{V}, I_C = 20\text{mA}, R_L = 100\Omega, -3\text{dB}$
Rise time	t_r	-	-	300	μs	$V_{CE} = 2\text{V}, I_C = 20\text{mA}, R_L = 100\Omega$
Fall time	t_f	-	-	100	μs	

* Typical values at $T_a = 25^\circ\text{C}$

Typical Electro-Optical Characteristics Curves

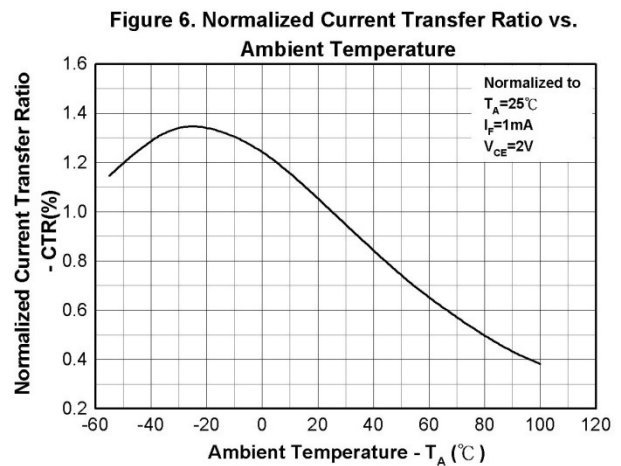
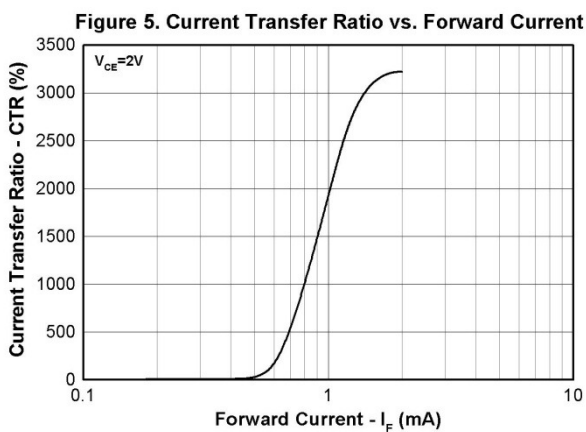
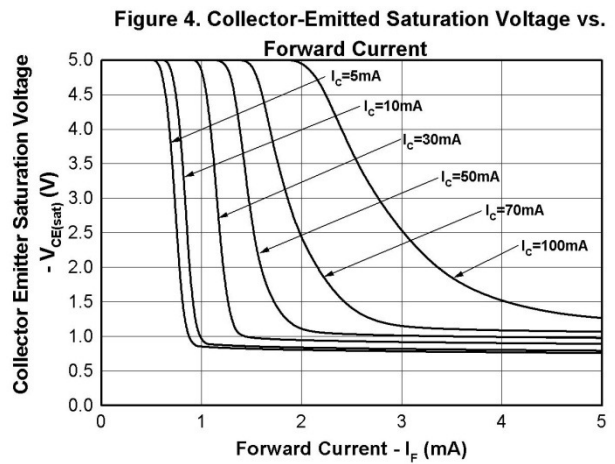
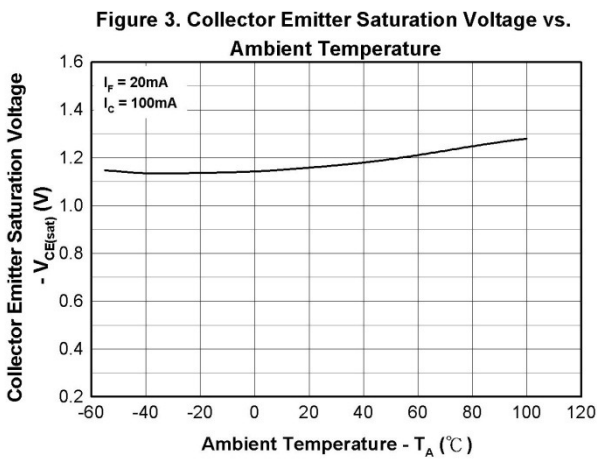
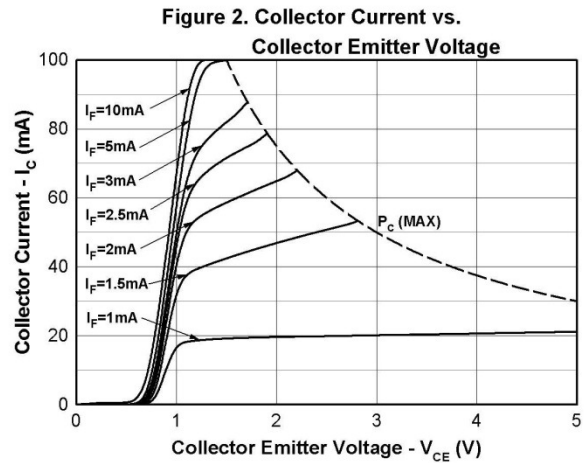
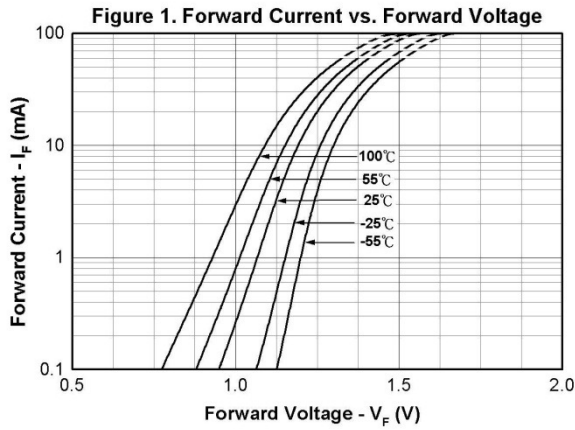


Figure 7. Collector Dark Current vs. Ambient Temperature

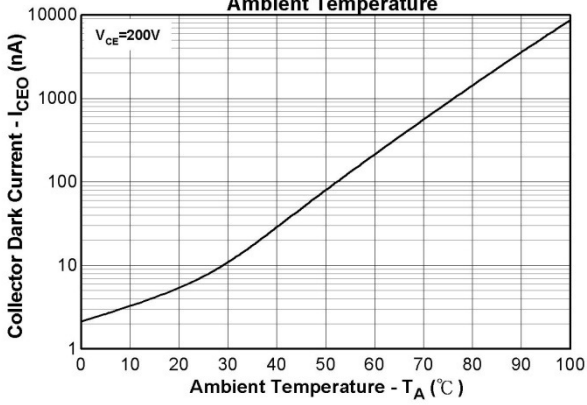


Figure 8. Response Time vs. Load Resistance

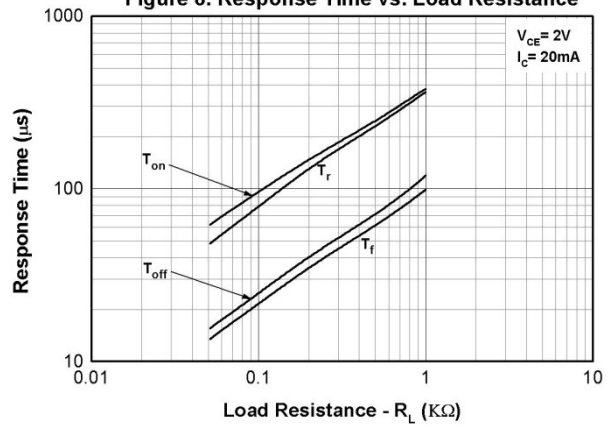
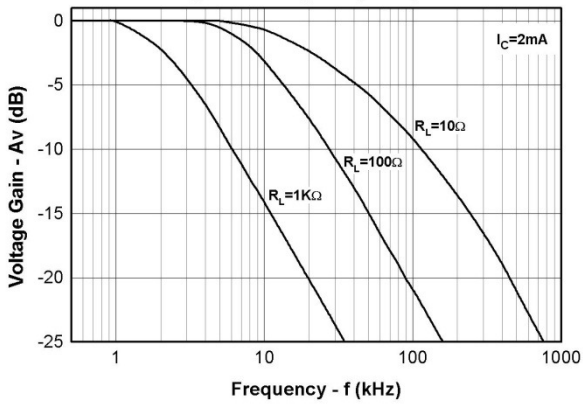


Figure 9. Frequency Response



**Order Informatio
Part Number**

EL852X(Y)-V

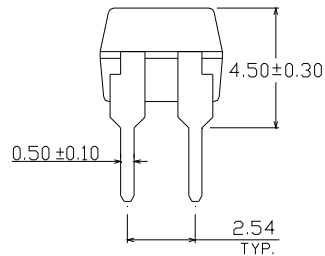
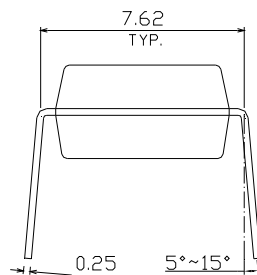
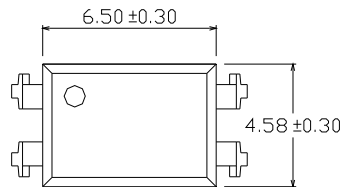
Note

- X = Lead form option (S, S1, M or none)
- Y = Tape and reel option (TA, TB ,TU, TD or none).
- V = VDE safety (optional).

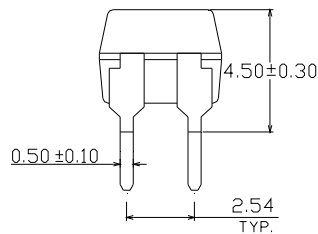
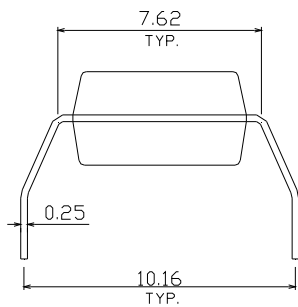
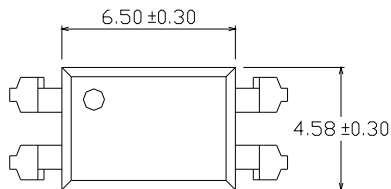
Option	Description	Packing quantity
None	Standard DIP-4	100 units per tube
M	Wide lead bend (0.4 inch spacing)	100 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	1000 units per reel
S1 (TA)	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel
S1 (TB)	Surface mount lead form (low profile) + TB tape & reel option	1000 units per reel
S (TU)	Surface mount lead form + TU tape & reel option	1500 units per reel
S (TD)	Surface mount lead form + TD tape & reel option	1500 units per reel
S1 (TU)	Surface mount lead form (low profile) + TU tape & reel option	1500 units per reel
S1 (TD)	Surface mount lead form (low profile) + TD tape & reel option	1500 units per reel

Package Dimension (Dimensions in mm)

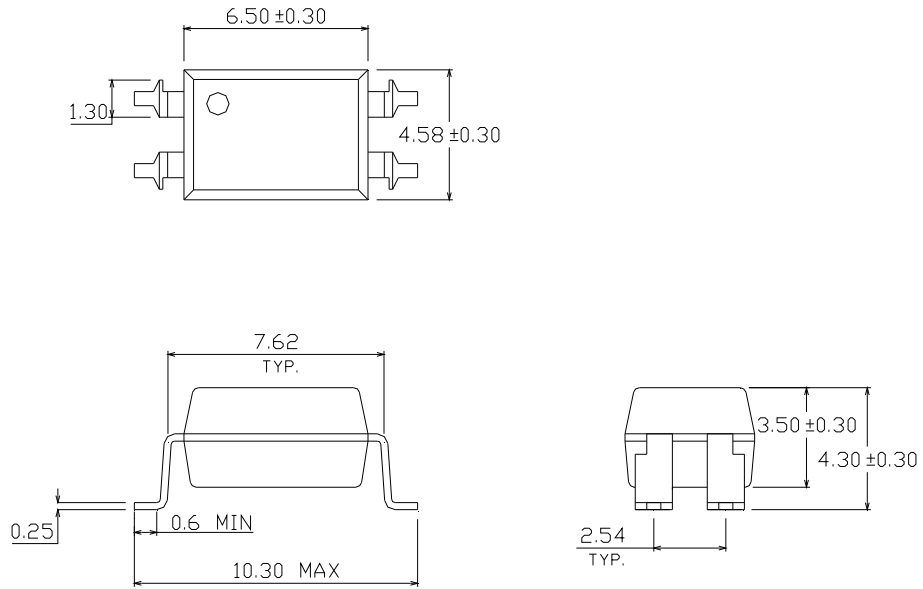
Standard DIP Type



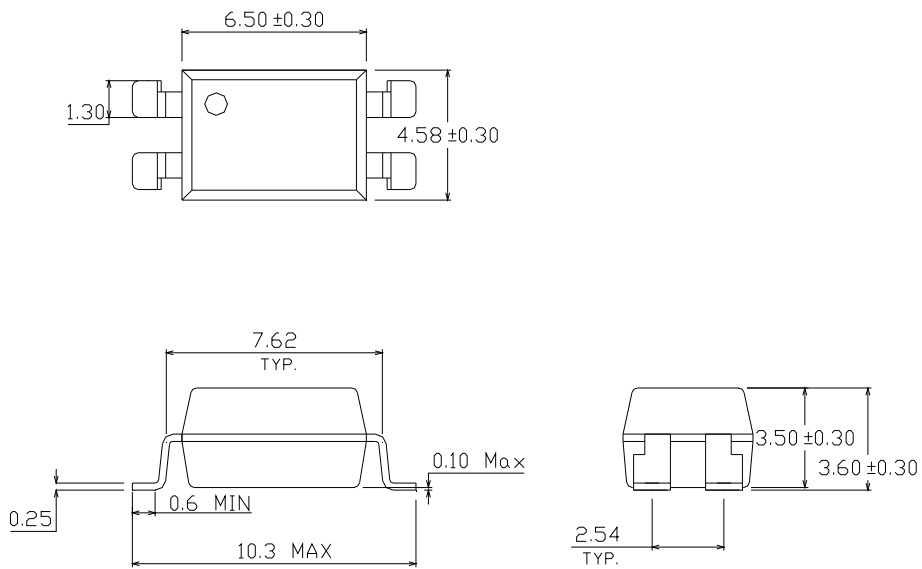
Option M Type



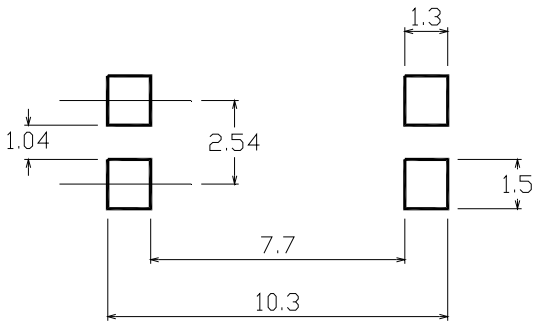
Option S Type



Option S1 Type



Recommended pad layout for surface mount leadform



Device Marking

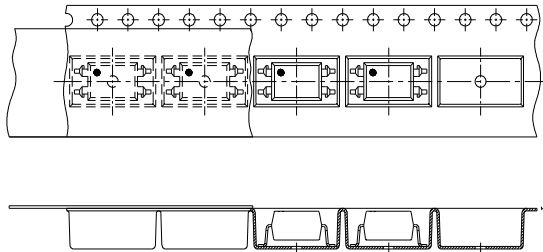


Notes

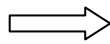
- EL denotes EVERLIGHT
- 852 denotes Device Number
- Y denotes 1 digit Year code
- WW denotes 2 digit Week code
- V denotes VDE optional

Tape & Reel Packing Specifications

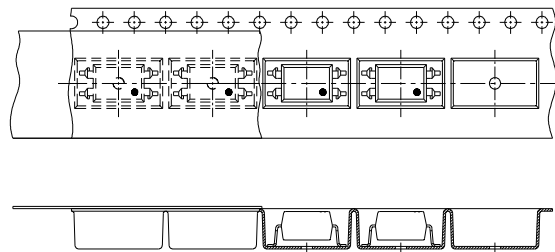
Option TA



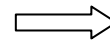
Direction of feed from reel



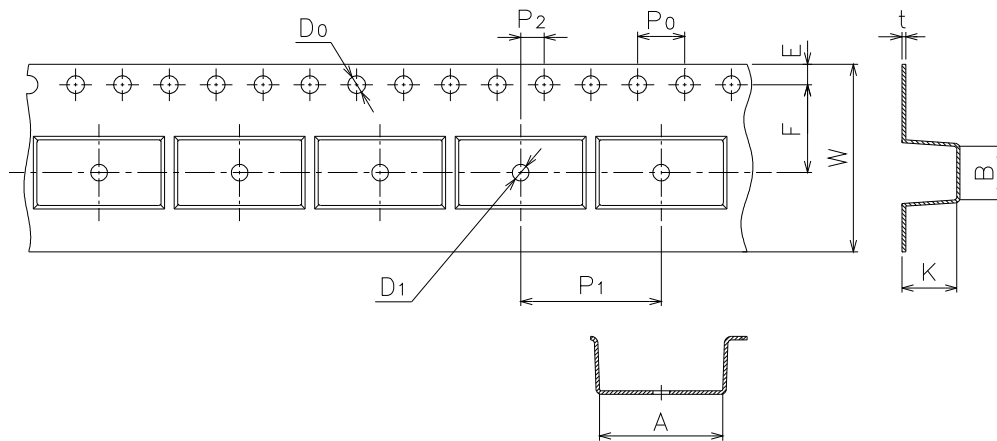
Option TB



Direction of feed from reel

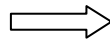
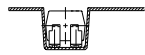
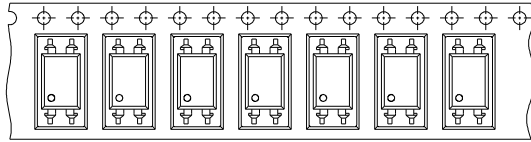


Tape dimensions



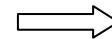
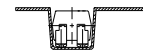
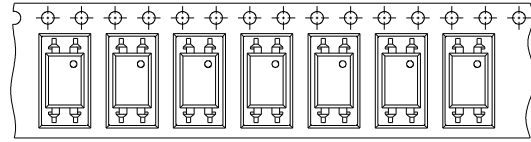
Dimension No.	A	B	Do	D1	E	F
Dimension(mm)	10.5±0.1	4.65±0.1	1.55±0.1	1.50±0.1	1.75±0.1	7.5±0.1
Dimension No.	Po	P1	P2	t	W	K
Dimension(mm)	4.0±0.1	12.0±0.1	2.0±0.1	0.35±0.1	16.0±0.3	4.75±0.1

Option TD



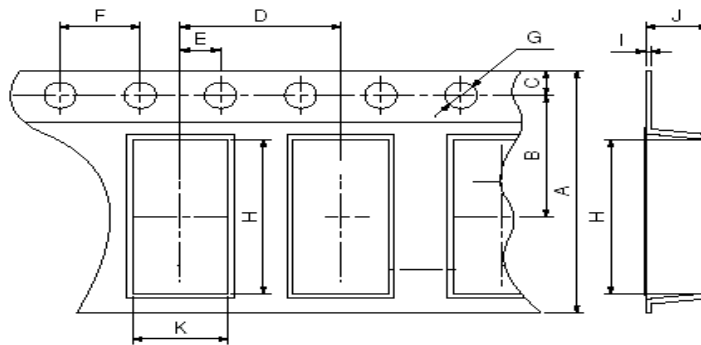
Direction of feed from reel

Option TU



Direction of feed from reel

Tape dimensions

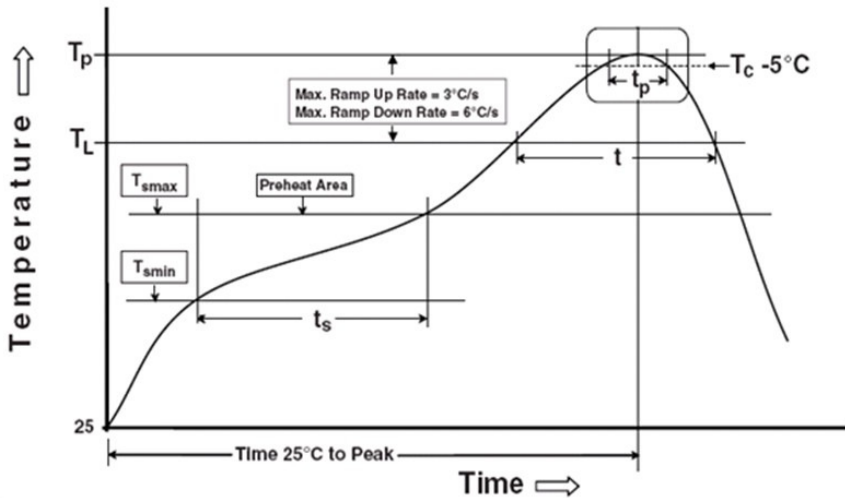


Dimension No.	A	B	C	D	E	F
Dimension(mm)	16.00±0.3	7.5±0.1	1.75±0.1	8.0±0.1	2.0±0.1	4.0±0.1
Dimension No.	G	H	I	J	K	
Dimension(mm)	1.55±0.05	10.4±0.1	0.4±0.05	4.60±0.1	5.1±0.1	

Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

Reference: IPC/JEDEC J-STD-020D

Preheat

Temperature min (T_{smin})	150 °C
Temperature max (T_{smax})	200 °C
Time (T_{smin} to T_{smax}) (t_s)	60-120 seconds
Average ramp-up rate (T_{smax} to T_p)	3 °C/second max

Other

Liquidus Temperature (T_L)	217 °C
Time above Liquidus Temperature (t_L)	60-100 sec
Peak Temperature (T_p)	260 °C
Time within 5 °C of Actual Peak Temperature: $T_p - 5^\circ\text{C}$	30 s
Ramp- Down Rate from Peak Temperature	6 °C /second max.
Time 25 °C to peak temperature	8 minutes max.
Reflow times	3 times

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